LL1.5 THRU LL2.4

Voltage Stabilizers

FEATURES

- Silicon Planar Stabilizer Diodes
- Monolithic integrated analog circuits in MiniMELF case, designed for small power stabilizer and limitation circuits, providing low dynamic resistance and high-quality stabilization performance as well as low noise. In the reverse direction, these devices show the behavior of forward-biased silicon diodes.
- The end of the device marked with the cathode ring is to be connected: LL1.5 and LL2 to the negative pole of the supply voltage LL2.4 to the positive pole of the supply voltage
- These diodes are also available in DO-35 case with the type designation ZTE1.5 ... ZTE2.4.

MECHANICAL DATA

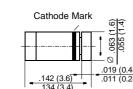
Case: MiniMELF Glass Case (SOD-80) **Weight:** approx. 0.05 g

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Value	Unit
Operating Current see Table "Characteristics"			
Inverse Current	IF	100	mA
Power Dissipation at $T_{amb} = 25 \text{ °C}$	P _{tot}	300 ¹⁾	mW
Junction Temperature	Tj	150	°C
Storage Temperature Range	T _S	-55 to +150	°C
¹⁾ Valid provided that electrodes are kept at ambient terr	nperature.		1





Dimensions in inches and (millimeters)

MiniMELE

LL1.5 THRU LL2.4

ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

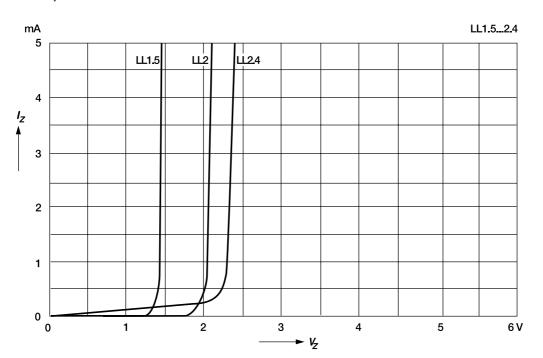
	Symbol	Min.	Тур.	Max.	Unit
Forward Voltage at $I_F = 10 \text{ mA}$	V _F	-	_	1.1	V
Temperature Coefficient of the stabilized voltage at I _Z = 5 mA LL1.5, LL2 LL2.4	α _{VZ} α _{VZ}	-	-26 -34		10 ⁻⁴ /K 10 ⁻⁴ /K
Thermal Resistance Junction to Ambient Air	R _{thJA}	_	_	0.41)	K/mW
¹⁾ Valid provided that electrodes are kept at ambie	ent temperature	э.			-

Туре	Operating voltage at $I_Z = 5 \text{ mA}^{1}$	Dynamic resistance at I _Z = 5 mA	Permissible operating current at $T_{amb} = 25 \text{ °C}^{2)}$	
	V _Z V	r _{zj} Ω	I _Z max. mA	
LL1.5	1.35 1.55	13 (< 20)	120	
LL2	2.0 2.3	18 (< 30)	120	
LL2.4	2.2 2.56	14 (< 20)	120	

²⁾ Valid provided that electrodes are kept at ambient temperature.



RATINGS AND CHARACTERISTIC CURVES LL1.5 THRU LL2.4

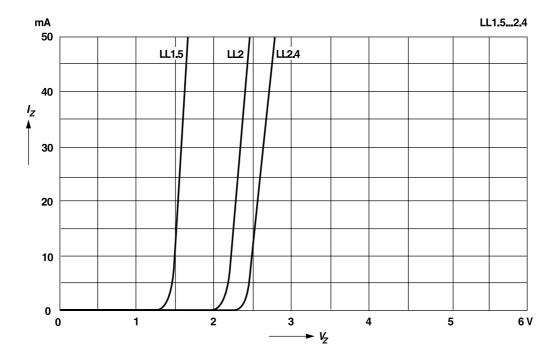


Breakdown characteristics

T_j = constant (pulsed)

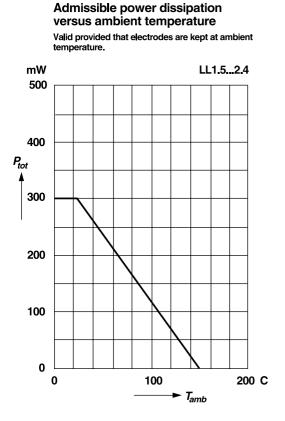
Breakdown characteristics

T_j = constant (pulsed)



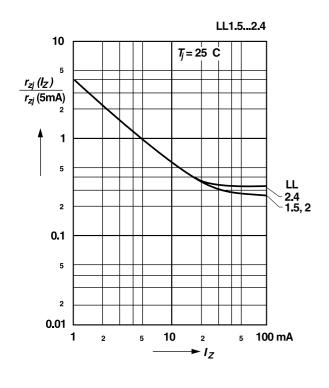


RATINGS AND CHARACTERISTIC CURVES LL1.5 THRU LL2.4



V LL1.5...2.4 100 $r_{zu} = r_{zj} + r_{zth}$ 7 $r_{zth} = a_{VZ} \cdot R_{thA} \cdot V_Z^2$ *l_z =* 5 mA – 5 $T_{i} = 25 \text{ C}$ 4 r_z 3 2 ш 2 ŗzj LL1.5 10 7 r_{zu} 5 4 r_{zth}(negative) 3 ۲LL2 2 LL1.5 1 0 1 2 3 4 5 V \blacktriangleright V_Z at I_Z = 5 mA

Dynamic resistance versus operating current, normalized





Dynamic resistance versus operating voltage